SSCN123GS9

NPN Type Digital Transistor (built-in resistors)

➢ Features

VCC	VIN	IO	R1	R2/R1 Typ.
50V	-5~+12V	100mA	2.2kΩ	21

➢ Description

Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).

The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects. Only the on/off conditions need to be set for operation, making the device design easy.

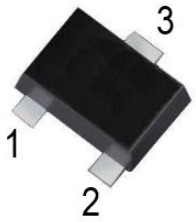
➢ Applications

- Amplifying signal
- Electronic switch
- Oscillating circuit
- Variable resistance

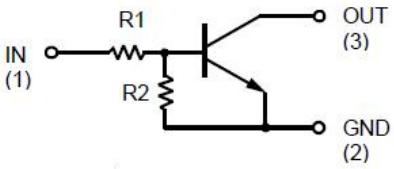
➢ Ordering Information

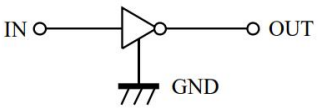
Device	Package	Shipping
SSCN123GS9	SOT-723	8000/Reel

➢ Pin configuration

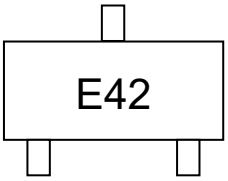


SOT-723





Circuit Diagram



Marking (Top View)

➢ Absolute Maximum Ratings(T_A=25℃ unless otherwise noted)

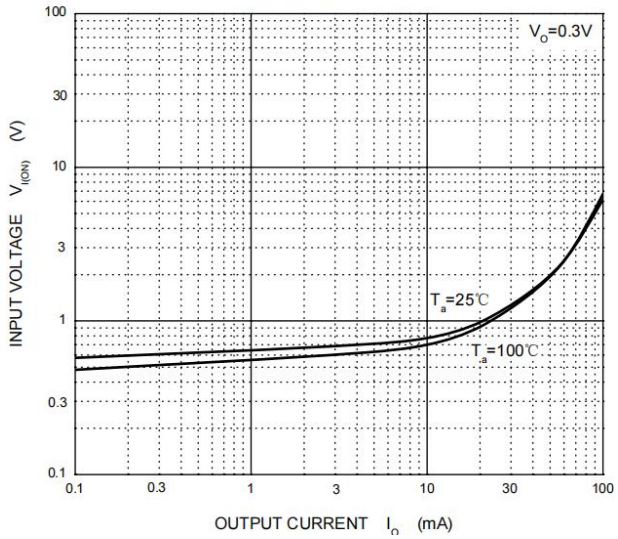
Parameter	Symbol	Value	Unit
Supply Voltage	V_{CC}	50	V
Input Voltage	V_{IN}	-5 to +12	V
Output current	I_O	100	mA
Power Dissipation	P_D	100	mW
Junction Temperature	T_J	-55 to 150	℃
Storage Temperature	T_{STG}	-55 to 150	℃

➢ Electrical Characteristics (T_A=25℃ unless otherwise noted)

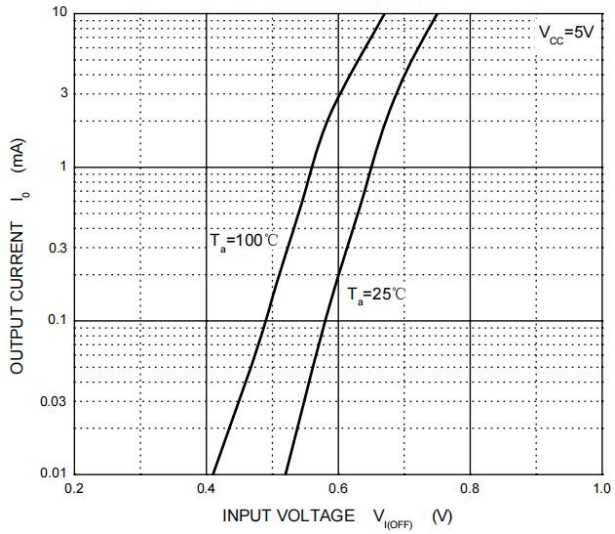
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Input Voltage	$V_{I(off)}$	V_{CC} = 5V, I_O=0.1mA	0.5			V
	$V_{I(on)}$	V_{CC} = 0.3V, I_O = 5mA			1.1	V
Output Voltage	$V_{O(on)}$	I_O/I_I = 5mA/0.25mA			0.3	V
Input Current	I_I	V_I = 5V			3.6	mA
Output Current	$I_{O(off)}$	V_{CC} = 50V, V_I = 0V			0.1	uA
DC Current Gain	G_1	V_O = 5V, I_O = 10mA	80			
Input Resistance	R_1		1.54	2.2	2.86	KΩ
Resistance Ration	R_2/R_1		17	21	26	
Transition Frequency	f_T	V_O=10V,I_O=5mA,f=100MHz		250		MHz

➢ Typical Performance Characteristics (T_A=25℃ unless otherwise noted)

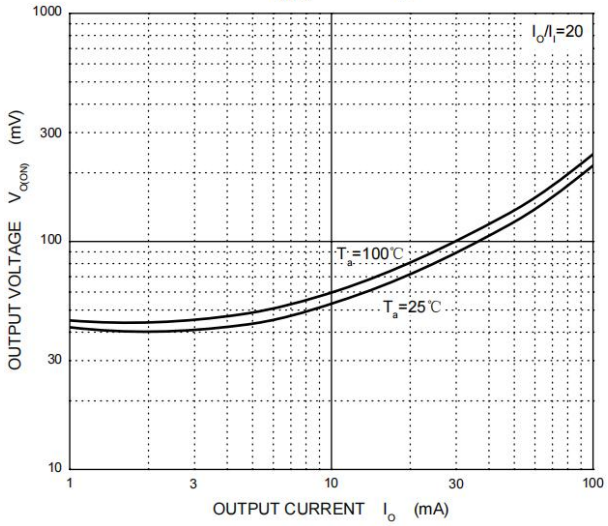
ON Characteristics



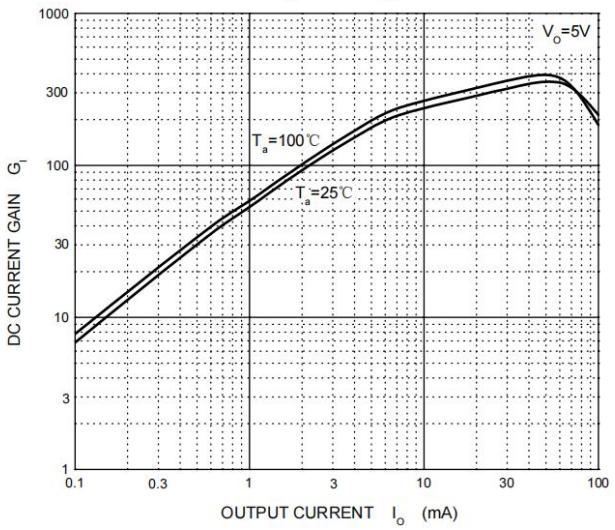
OFF Characteristics



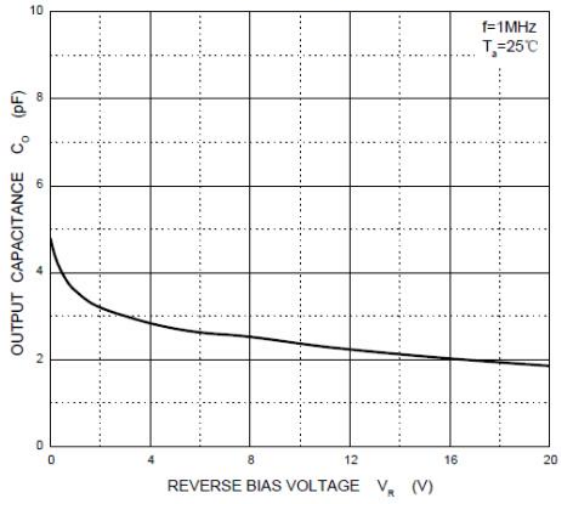
$V_{O(ON)}$ — I_O



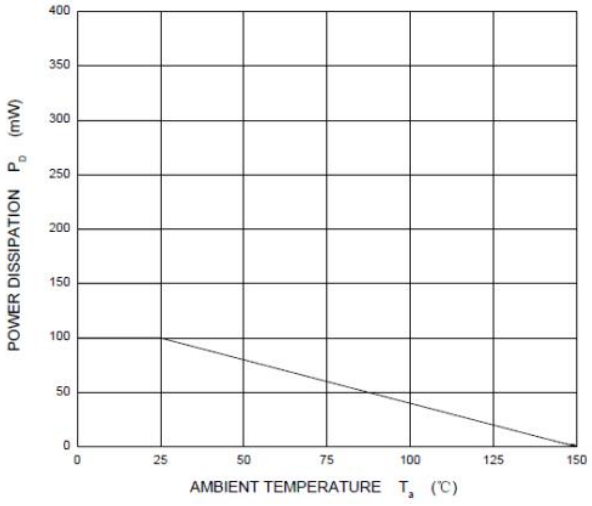
G_I — I_O



C_O — V_R

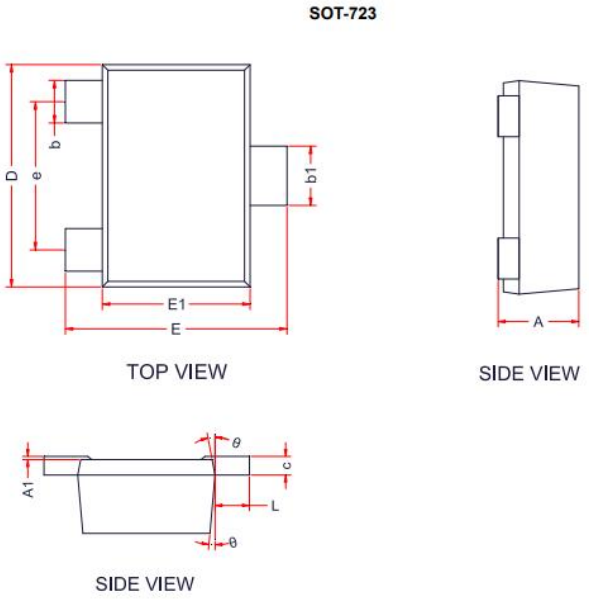


P_D — T_a



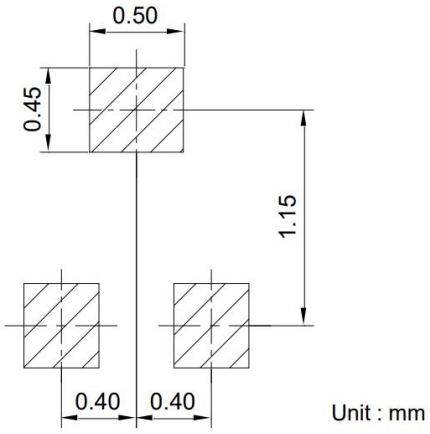
➢ Package Information

● Mechanical Data



DIM	Millimeters		
	Min.	Typ.	Max.
A	0.43	-	0.55
A1	0.00	-	0.05
b1	0.27		0.37
b	0.17	-	0.27
c	0.08	0.13	0.18
D	1.15	1.20	1.25
E	1.15	1.20	1.25
E1	0.75	0.8	0.85
e	0.80Ref.		
L1	0.15	0.2	0.25
θ	7°Ref.		

Recommended Pad outline



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